TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

# 2SK711

**High Frequency Amplifier Applications** AM High Frequency Amplifier Applications Audio Frequency Amplifier Applications

• High  $|Y_{fs}|$ :  $|Y_{fs}| = 25 \text{ mS (typ.)}$ 

Low  $C_{iss}$ :  $C_{iss} = 7.5 pF$  (typ.)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	$V_{GDS}$	-20	V
Gate current	IG	10	mA
Drain power dissipation	P <sub>D</sub>	150	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the

Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

	Unit: mm
1. SOURC 2. DRAIN 3. GATE	
JEDEC	TO-236MOD
JEITA	SC-59
TOSHIBA	2-3F1B

Weight: 0.012 g (typ.)

### **Electrical Characteristics (Ta = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS} = -15 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	-1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0 \text{ V}, I_G = -100 \mu\text{A}$	-20	_	_	V
Drain current	I <sub>DSS</sub> (Note)	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 0 V	6	_	32	mA
Gate-source cut-off voltage	V <sub>GS</sub> (OFF)	$V_{DS} = 5 \text{ V}, I_{D} = 1 \mu A$	_	_	-2.5	V
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ kHz}$	15	25	_	mS
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	7.5	10	pF
Reverse transfer capacitance	C <sub>rss</sub>	$V_{DS} = 5 \text{ V}, I_D = 0 \text{ mA}, f = 1 \text{ MHz}$	_	2	3	pF

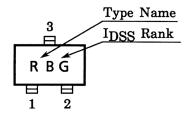
Note: I<sub>DSS</sub> classification

GR: 6~12 mA, BL: 10~20 mA, V: 16~32 mA

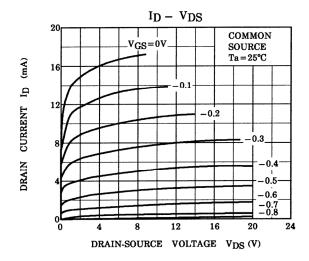
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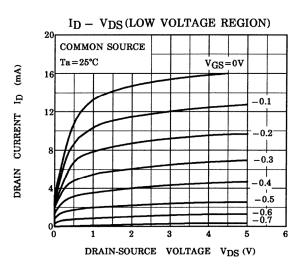
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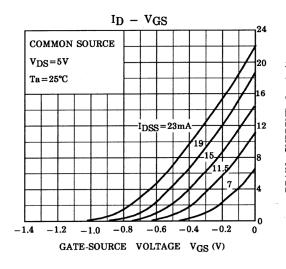
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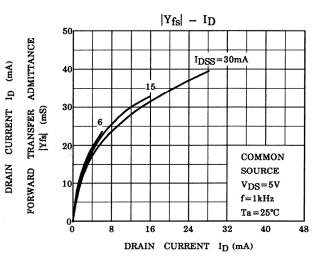


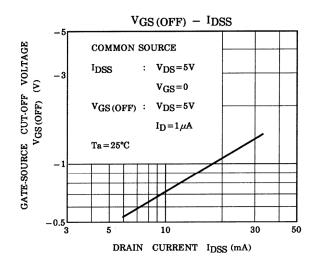
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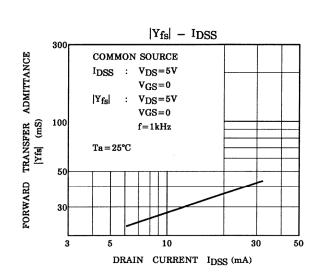




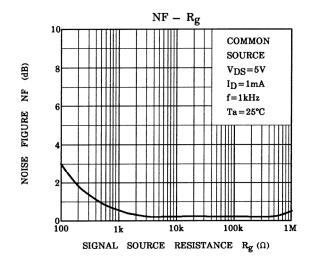


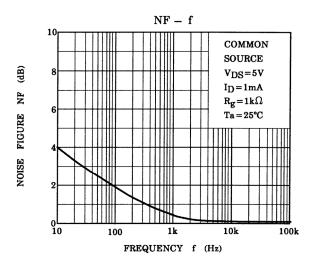


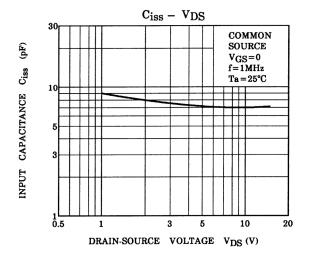


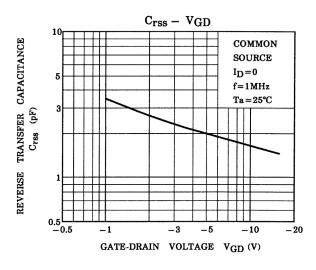


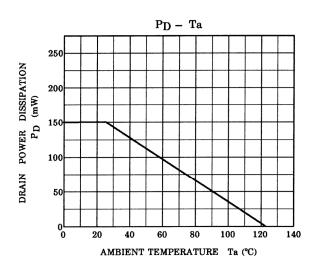
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20070701-EN GENERAL

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